NSN 5962-01-076-6610

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View Online at https://aerobasegroup.com/nsn/5962-01-076-6610

Body Length:
0.440 inches
Body Width:
Between 0.240 inches and 0.325 inches
Body Height:
0.085 inches
Maximum Power Dissipation Rating:
910.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/storage and programmable and programmed and bipolar and 3-state output
and schottky and high speed and expandable and w/buffered output and w/decoded output and w/enable and w/disable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
75.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
82577-932820 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
16 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

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